

BC817-16QCH-QZ Datasheet

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DiGi Electronics Part Number BC817-16QCH-QZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC817-16QCH-QZ

Description TRANS NPN 45V 0.5A DFN1412D-3

Detailed Description Bipolar (BJT) Transistor NPN 45 V 500 mA 100MHz 4

55 mW Surface Mount, Wettable Flank DFN1412D-3



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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|--|--|
| BC817-16QCH-QZ | Nexperia USA Inc. |
| Series: | Product Status: |
| BC817QCH-Q | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| NPN | 500 mA |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, Ic: |
| 45 V | 700mV @ 50mA, 500mA |
| Current - Collector Cutoff (Max): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 100nA (ICBO) | 100 @ 100mA, 1V |
| Power - Max: | Frequency - Transition: |
| 455 mW | 100MHz |
| Operating Temperature: | Grade: |
| 175°C (TJ) | Automotive |
| Qualification: | Mounting Type: |
| AEC-Q101 | Surface Mount, Wettable Flank |
| Package / Case: | Supplier Device Package: |
| 3-XDFN Exposed Pad | DFN1412D-3 |
| Base Product Number: | |
| BC817 | |

Environmental & Export classification

8541.21.0075

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |

1. General description

NPN general-purpose transistor in an ultra small DFN1412D-3 (SOT8009) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

| Type number | Package | PNP complement | | |
|---------------|------------|----------------|---------|---------------|
| | Name | JEDEC | Version | |
| BC817-16QCH-Q | DFN1412D-3 | MO-340CA | SOT8009 | BC807-16QCH-Q |
| BC817-25QCH-Q | | | | BC807-25QCH-Q |
| BC817-40QCH-Q | - | | | BC807-40QCH-Q |

2. Features and benefits

- · High power dissipation capability
- High current
- Three current gain selections
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- Smaller footprint compared to conventional leaded SMD packages
- Low package height of 0.5 mm
- High-temperature applications up to 175 °C
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- General-purpose switching and amplification
- Space restricted applications

4. Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---------------------------|---|---------|-----|-----|------|
| V _{CEO} | collector-emitter voltage | open base; T _{amb} = 25 °C | - | - | 45 | V |
| I _C | collector current | T _{amb} = 25 °C | - | - | 500 | mA |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C | - | - | 1 | Α |
| h _{FE} | DC current gain | | | | | · |
| | BC817-16QCH-Q | V _{CE} = 1 V; I _C = 100 mA T _{amb} = 25 °C | [1] 100 | - | 250 | |
| | BC817-25QCH-Q | | 160 | - | 400 | |
| | BC817-40QCH-Q | | 250 | - | 600 | |

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



45 V, 500 mA NPN general-purpose transistors

5. Pinning information

Table 3. Pinning

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|---|----------------|
| 1 | В | base | 4 | C |
| 2 | Е | emitter | 3 | В |
| 3 | С | collector | | □ ¬\ |
| | | | 1 2 | É sym021 |
| | | | Transparent top view DFN1412D-3 (SOT8009) | |

6. Ordering information

Table 4. Ordering information

| Type number | Package | ^P ackage | | | | |
|---------------|------------|---|------------|--|--|--|
| | Name | Description | Version | | | |
| BC817-16QCH-Q | DFN1412D-3 | DFN1412D-3: plastic thermal enhanced ultra thin small outline | SOT8009 | | | |
| BC817-25QCH-Q | | package; no leads; 3 terminals; body: 1.4 x 1.2 x 0.5 mm | (MO-340CA) | | | |
| BC817-40QCH-Q | | | | | | |

7. Marking

Table 5. Marking

| Type number | Marking code |
|---------------|--------------|
| BC817-16QCH-Q | 8V |
| BC817-25QCH-Q | 8W |
| BC817-40QCH-Q | 8Y |

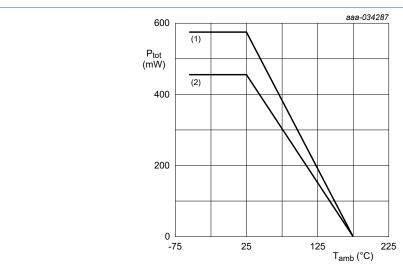
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|---|---|-----|-----|------|
| V _{CBO} | collector-base voltage | open emitter; T _{amb} = 25 °C | | - | 50 | V |
| V _{CEO} | collector-emitter voltage | open base; T _{amb} = 25 °C | | - | 45 | V |
| V_{EBO} | emitter-base voltage | open collector; T _{amb} = 25 °C | | - | 5 | V |
| Ic | collector current | T _{amb} = 25 °C | T _{amb} = 25 °C | | 500 | mA |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms; T _{amb} = | single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C | | 1 | Α |
| I _{BM} | peak base current | single pulse; t _p ≤ 1 ms; T _{amb} = | single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C | | 200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 455 | mW |
| | | | [2] | - | 575 | mW |
| Tj | junction temperature | | | - | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -65 | 175 | °C |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint.



- (1) FR4 PCB; single-sided 70 µm copper, tin-plated and standard footprint
- (2) FR4 PCB; single-sided 35 µm copper, tin-plated and standard footprint

Fig. 1. Power derating curves for SOT8009

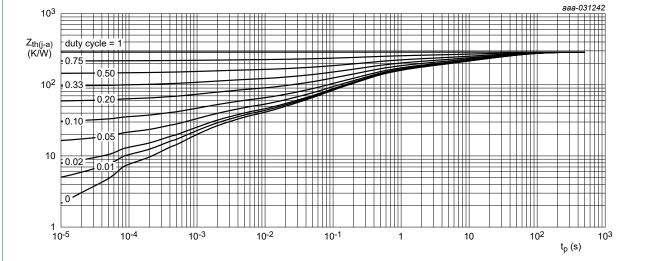
45 V, 500 mA NPN general-purpose transistors

9. Thermal characteristics

Table 7. Thermal characteristics

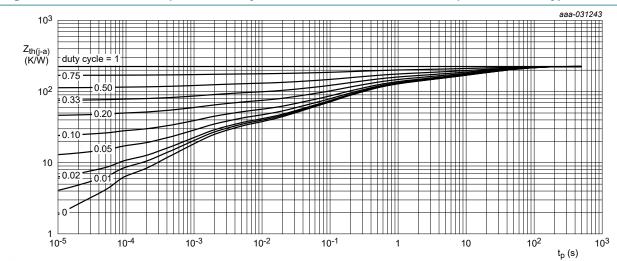
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|---|--------------------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in nee an, | [1] | - | - | 329 | K/W |
| | | $T_{amb} = 25 \degree C$ | [2] | - | - | 261 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided 35µm copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided 70µm copper, tin-plated and standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 500 mA NPN general-purpose transistors

10. Characteristics

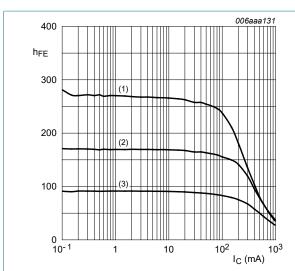
Table 8. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|--|-------|-----|-----|------|
| $V_{(BR)CBO}$ | collector-base breakdown voltage | I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C | 50 | - | | V |
| $V_{(BR)CEO}$ | collector-emitter breakdown voltage | I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C | 45 | - | | V |
| V _{(BR)EBO} | emitter-base breakdown voltage | I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C | 5 | - | | V |
| I _{CBO} | collector-base | V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C | - | - | 100 | nA |
| | cut-off current | V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C | - | - | 5 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C | | - | 100 | nA |
| h _{FE} | DC current gain | | | ' | | |
| | BC817-16QCH-Q | $V_{CE} = 1 \text{ V}; I_{C} = 100 \text{ mA}; T_{amb} = 25 \text{ °C}$ [2] |] 100 | - | 250 | |
| | BC817-25QCH-Q | | 160 | - | 400 | |
| | BC817-40QCH-Q | _ | 250 | - | 600 | |
| | | V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C [|] 40 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$ |] - | - | 700 | mV |
| V_{BE} | base-emitter voltage | V_{CE} = 1 V; I_{C} = 500 mA; T_{amb} = 25 °C [1] | | - | 1.2 | V |
| f _T | transition frequency | $V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | | - | - | MHz |
| C _c | collector capacitance | $V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ | - | 3 | - | pF |

^[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

Product data sheet

^[2] V_{BE} decreases by about 2 mV/K with increasing temperature.



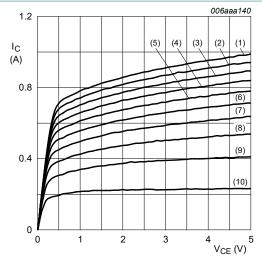
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16QCH-Q: DC current gain as a function of collector current; typical values



(1)
$$I_B = 16.0 \text{ mA}$$

(2)
$$I_B = 14.4 \text{ mA}$$

$$(3) I_B = 12.8 \text{ mA}$$

$$(4) I_B = 11.2 \text{ mA}$$

$$(5) I_B = 9.6 \text{ mA}$$

(6)
$$I_B = 8.0 \text{ mA}$$

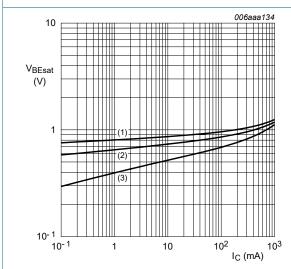
$$(7) I_B = 6.4 \text{ mA}$$

(8)
$$I_B = 4.8 \text{ mA}$$

(9)
$$I_B = 3.2 \text{ mA}$$

(10)
$$I_B = 1.6 \text{ mA}$$

Fig. 5. BC817-16QCH-Q: Collector current as a function of collector-emitter voltage; typical values

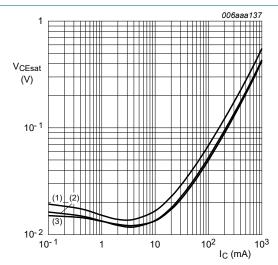


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. BC817-16QCH-Q: Base-emitter saturation voltage as a function of collector current; typical values



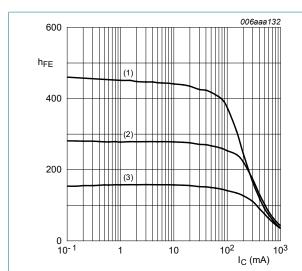
$$IC/IB = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 7. BC817-16QCH-Q: Collector-emitter saturation voltage as a function of collector current; typical values



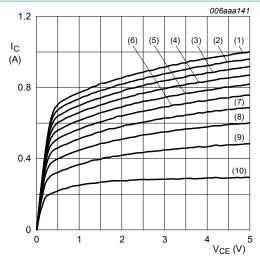
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 8. BC817-25QCH-Q: DC current gain as a function of collector current; typical values



(1)
$$I_B = 13.0 \text{ mA}$$

(2)
$$I_B = 11.7 \text{ mA}$$

$$(3) I_B = 10.4 \text{ mA}$$

$$(4) I_B = 9.1 mA$$

$$(5) I_B = 7.8 \text{ mA}$$

(6)
$$I_B = 6.5 \text{ mA}$$

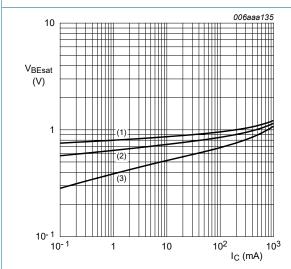
(7)
$$I_B = 5.2 \text{ mA}$$

(8)
$$I_B = 3.9 \text{ mA}$$

(9)
$$I_B = 2.6 \text{ mA}$$

(10)
$$I_B = 1.3 \text{ mA}$$

Fig. 9. BC817-25QCH-Q: Collector current as a function of collector-emitter voltage; typical values

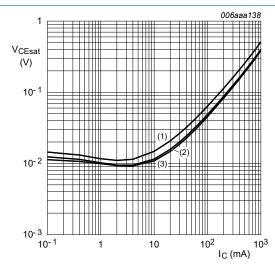


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 10. BC817-25QCH-Q: Base-emitter saturation voltage as a function of collector current; typical values

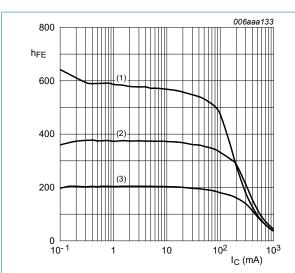


(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 11. BC817-25QCH-Q: Collector-emitter saturation voltage as a function of collector current; typical values



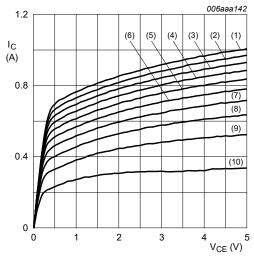
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC817-40QCH-Q: DC current gain as a function of collector current; typical values



$$(1) I_B = 12.0 \text{ mA}$$

$$(2) I_B = 10.8 \text{ mA}$$

(3)
$$I_B = 9.6 \text{ mA}$$

$$(4) I_B = 8.4 \text{ mA}$$

$$(5) I_B = 7.2 \text{ mA}$$

(6)
$$I_B = 6.0 \text{ mA}$$

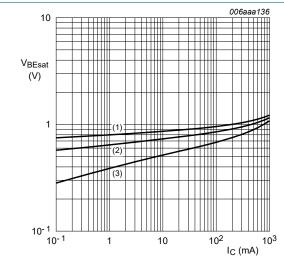
$$(7) I_B = 4.8 \text{ mA}$$

(8)
$$I_B = 3.6 \text{ mA}$$

(9)
$$I_B = 2.4 \text{ mA}$$

$$(10) I_B = 1.2 mA$$

Fig. 13. BC817-40QCH-Q: Transition frequency as a function of collector current; typical values

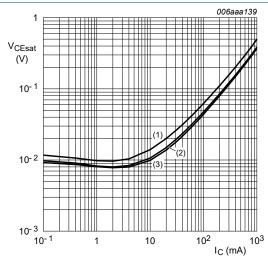


(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 14. BC817-40QCH-Q: Base-emitter saturation voltage as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 15. BC817-40QCH-Q: Collector-emitter saturation voltage as a function of collector current; typical values

11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

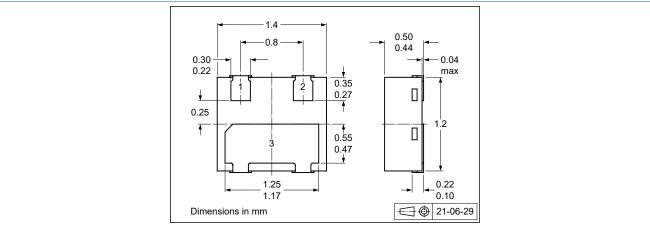
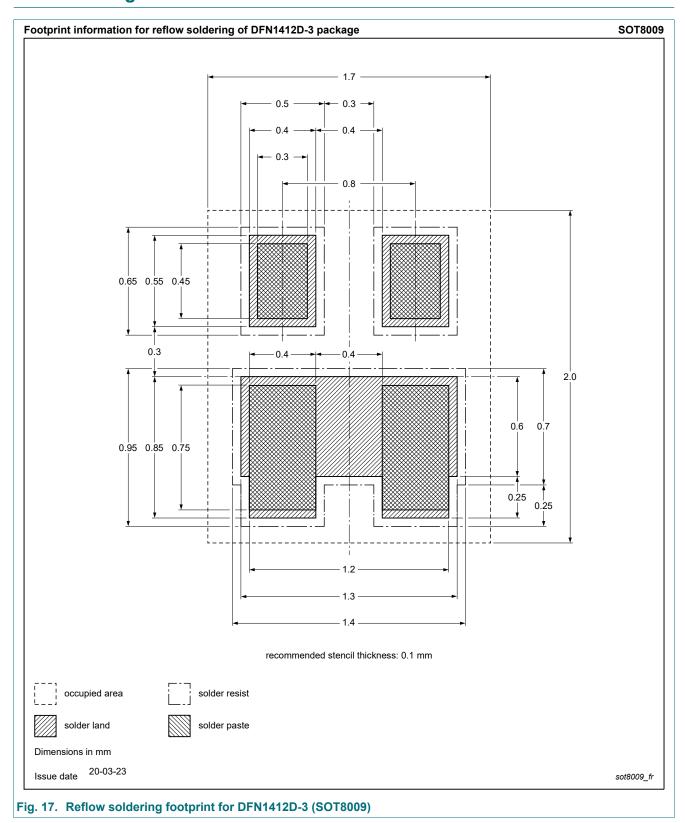


Fig. 16. Package outline DFN1412D-3 (SOT8009)

13. Soldering



Nexperia

BC817QCH-Q series

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14. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------------|--------------|--------------------|---------------|------------|
| BC817QCH-Q_SER v.1 | 20220125 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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For more information, please visit: http://www.nexperia.com
For sales office addresses, please send an email to: salesaddresses@nexperia.com
Date of release: 25 January 2022

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